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1S2076A

Silicon Epitaxial Planar Diode for High Speed Switching



ADE-208-146B (Z)

Rev.2 Oct. 2000

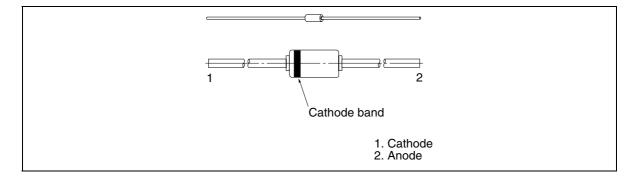
Features

- Low capacitance. (C = 3.0 pF max)
- Short reverse recovery time. $(t_{rr} = 8.0 \text{ ns max})$
- High reliability with glass seal.

Ordering Information

Type No.	Cathode band	Package Code
1S2076A	Navy Blue	DO-35

Pin Arrangement



1S2076A

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Peak reverse voltage	V _{RM}	70	V
Reverse voltage	V _R	60	V
Peak forward current	I _{FM}	450	mA
Non-Repetitive peak forward surge current	*	1	А
Average forward current	I _o	150	mA
Power dissipation	Pd	250	mW
Junction temperature	Tj	175	°C
Storage temperature	Tstg	-65 to +175	°C

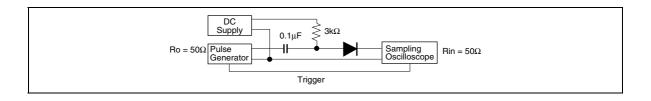
Note: Within 1s forward surge current.

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V _F	0.64	_	0.8	V	I _F = 10 mA
Reverse current	I _R		_	0.1	μΑ	V _R = 30 V
Capacitance	С	_	_	3.0	pF	V _R = 1 V, f = 1 MHz
Reverse recovery time	t _{rr} *	_	_	8.0	ns	$I_{\rm F} = I_{\rm R} = 10 \text{ mA}, \text{ Irr} = 1 \text{ mA}$

Note: Reverse recovery time test circuit



Main Characteristic

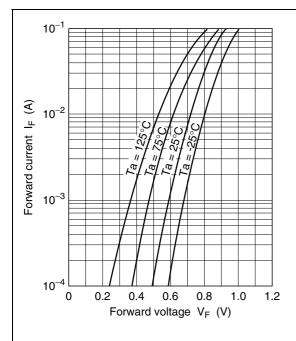
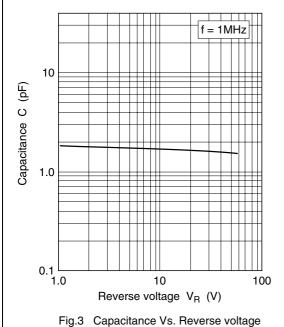


Fig.1 Forward current Vs. Forward voltage



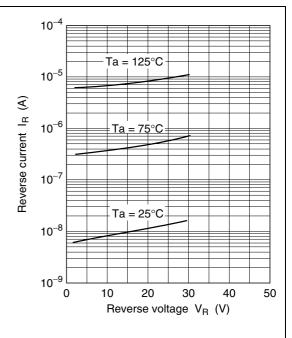
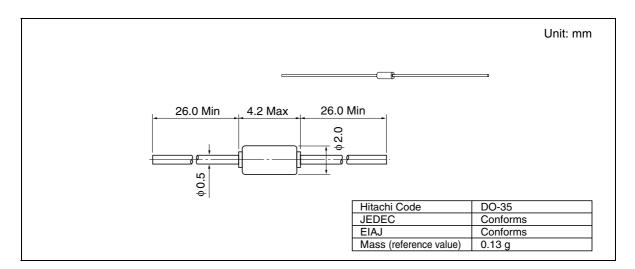


Fig.2 Reverse current Vs. Reverse voltage

1S2076A

Package Dimensions



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Sales Offices

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Hitachi, Ltd.

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URL

NorthAmerica http://semiconductor.hitachi.com/ Europe http://www.hitachi-eu.com/hel/ecg Asia http://sicapac.hitachi-asia.com Japan http://www.hitachi.co.jp/Sicd/indx.htm

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive San Jose, CA 95134 Tel: <1> (408) 433-1990 Maidenhead

Hitachi Europe Ltd. Electronic Components Group Whitebrook Park Lower Cookham Road Fax: <1>(408) 433-0223 Berkshire SL6 8YA, United Kingdom

Tel: <44> (1628) 585000 Fax: <44> (1628) 585200 Hitachi Europe GmbH

Electronic Components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany

Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00 Hitachi Tower 16 Collyer Quay #20-00 Singapore 049318 Tel: <65>-538-6533/538-8577 Fax: <65>-538-6933/538-3877 URL: http://www.hitachi.com.sg

Hitachi Asia Ltd.

Hitachi Asia Ltd (Taipei Branch Office) 4/F, No. 167, Tun Hwa North Road Hung-Kuo Building

Fax: <886>-(2)-2718-8180 Telex: 23222 HAS-TP URL: http://www.hitachi.com.tw

Taipei (105), Taiwan Tel: <886>-(2)-2718-3666

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Hitachi Asia (Hong Kong) Ltd.

7/F., North Tower

Hong Kong

World Finance Centre

Harbour City, Canton Road

Tsim Sha Tsui, Kowloon

Tel: <852>-(2)-735-9218

Fax: <852>-(2)-730-0281

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